TOSHIBA GTR Module Silicon N Channel IGBT

MG400Q1US41

High Power Switching Applications Motor Control Applications

• High input impedance

• High speed : $t_f = 0.5\mu s$ (Max.) $t_{rr} = 0.5\mu s$ (Max.)

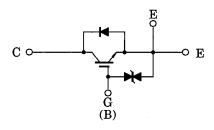
• Low saturation voltage

 $: V_{\text{CE(sat)}} = 4.0V \text{ (Max.)}$

• Enhancement-mode

• The electrodes are isolated from case.

Equivalent Circuit



Unit: mm 2-M4 2-M6 4-\$\phi 6.5 \pm 0.3 2-M4 2-M6 4-\$\phi 6.5 \pm 0.3 2-M4 2-M6 4-\$\phi 6.5 \pm 0.3 108 \pm 0.8 93 \pm 0.3 108 \pm 0.8 93 \pm 0.3 108 \pm 0.8 24 \pm 0.5 3 \pm 0.5 3 \pm 0.5 24 \pm 0.5 24 \pm 0.5 24 \pm 0.5 24 \pm 0.5 3 \pm 0.5 3 \pm 0.5 3 \pm 0.5 24 \pm 0.5 25 \pm 0.

Weight: 465g

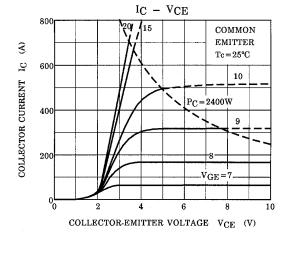
Maximum Ratings (Ta = 25°C)

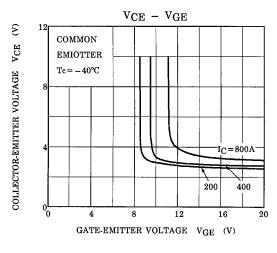
Characteristic		Symbol	Rating	Unit	
Collector-emitter voltage		V _{CES}	1200	V	
Gate-emitter voltage		V _{GES}	±20	V	
Collector current	DC	I _C	400	А	
	1ms	I _{CP}	800		
Forward current	DC	I _F	400	Α	
	1ms	I _{FM}	800		
Collector power dissipation (Tc = 25°C)		PC	2400	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	− 40 ~ 125	°C	
Isolation voltage		V _{Isol}	2500 (AC 1 minute)	V	
Screw torque (Terminal : M4 / M6 / mounting)		_	_ 2/3/3		

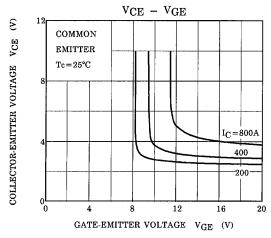


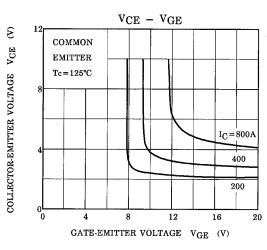
Electrical Characteristics (Ta = 25°C)

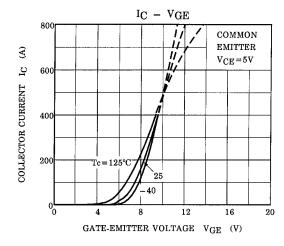
Char	acteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	te leakage current I _{GES} V _{GE} = ±20V, V _{CE} = 0			_	±40	μA	
Collector cut-off of	current	I _{CES}	V _{CE} = 1200V, V _{GE} = 0		_	4	mA
Gate-emitter cut-	itter cut-off voltage V _{GE (OFF)} I _C = 400mA, V _{CE} = 5V		3.0	_	6.0	V	
Collector-emitter	saturation voltage	V _{CE (sat)}	I _C = 400A, V _{GE} = 15V	_	3.0	4.0	V
Input capacitance	9	C _{ies}	V _{CE} = 10V, V _{GE} = 0, f = 1MHz		48000	_	pF
Switching time	Rise time	t _r	15V 2.4Ω C C C C C C C C C C C C C C C C C C C	_	0.3	0.6	μs
	Turn-on time	t _{on}		_	0.4	8.0	
	Fall time	t _f		_	0.2	0.5	
	Turn-off time	t _{off}		_	0.8	1.5	
Forward voltage		V _F		_	2.0	3.0	V
Reverse recovery time		t _{rr}	I _F = 400 A, V _{GE} = -10 V,P di / dt = 300 A / μs	_	0.25	0.5	μs
Thermal resistance		R _{th (j-c)}	Transistor	_	_	0.052	°C/W
			Diode	_	_	0.2]

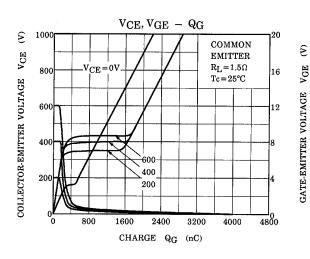


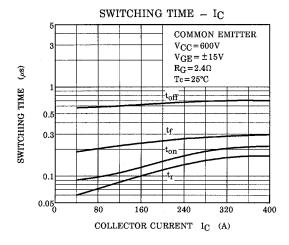


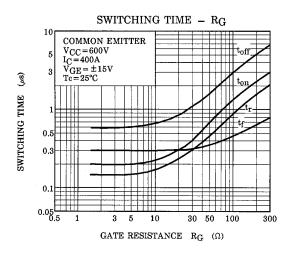


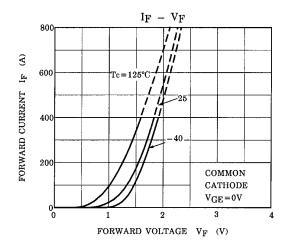


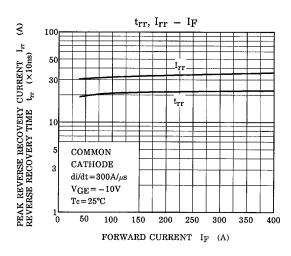


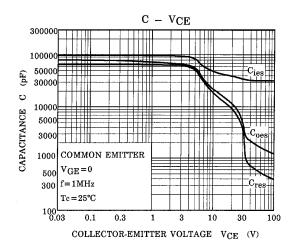


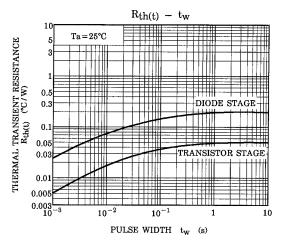


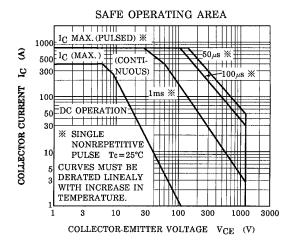


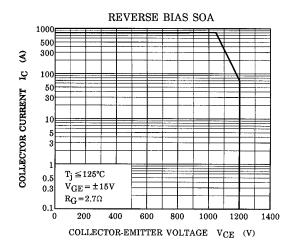












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